

L Number	Hits	Search Text	DB	Time stamp
1	2	6060714.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/13 15:49
2	0	6060714.pn. and (data adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/13 15:49
3	0	6060714.pn. and (common adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/13 15:50
-	0	capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:10
-	0	capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 15:55
-	1	capacitor and transistor and (planarization adj layer) and (conformal with (passivation adj layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 15:55
-	1	capacitor and transistor and (planarization adj layer) and (conformal same (passivation adj layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:11
-	1	capacitor and transistor and (planarization adj layer) and imager and conformal	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:12
-	12	capacitor and transistor and (planarization adj layer) and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:24
-	940	capacitor and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:24
-	225	(storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:25
-	0	438/240,155,200,239,256,279 393,399.cc1s. and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:19
-	0	257/295,312.cc1s. and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:23
-	5	438/240,155,200,239,256,279,393,399.cc1s. and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 11:55
-	5	438/240,155,200,239,256,279,393,394,395,396USPAT398,399cc1s. and (storage adj capacitor) and transistor and imager	US-PGPUB; EPO; JPO; DERWENT	2003/12/24 11:57
-	7	438/240,155,200,239,256,279,393,394,395,396USPAT398,399cc1s. and (capacitor) and transistor and imager	US-PGPUB; EPO; JPO; DERWENT	2003/12/24 11:57
-	8	257/295,296,297,298,299,300,301,302,303,304USPAT306,307,308,309,310,311,312.cc1s. and capacitor and transistor and imager	US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:42

-	0	250/370.09,580,214.1,ccls. and capacitor and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:21
-	0	250/370.09,580,214.1,ccls. and capacitor and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:45
-	52	250/370.09,580,214.1.ccls. and capacitor and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:46
-	1	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and conformal	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:46
-	16	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and passivation	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:54
-	1	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and passivation and (conformal same passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:54
-	0	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and passivation and (conformal same passivation) and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:54
-	15	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and passivation and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:55
-	0	250/370.09,580,214.1.ccls. and (storage adj capacitor) and transistor and imager and passivation and source and drain and planarization	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:56
-	10	250/370.09,580,214.1.ccls. and (storage adj capacitor) and transistor and imager and passivation and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:40
-	0	TW-540128-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:45
-	0	TW-0000540128-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:45
-	0	TW-5401280000-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:45
-	2	6362041.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:48
-	2	20030111740.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:50
-	2	6340638.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:20
-	2	6184121.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:53
-	2	5198694.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:07

-	0	200340107687.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:07
-	2	20030107687.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:08
-	0	KR-220058794-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:09
-	0	KR-220258794-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:10
-	0	KR-200258794-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:10
-	1	KR-2002058794-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:12
-	1	KR-2002004267-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:12
-	2	6051876.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:23
-	2	5688709.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:47
-	0	5198694.PN. and (data adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:49
-	0	5198694.PN. and (gate adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:49
-	0	6060714.pn. and (data adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:12
-	2	6060714.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:13
-	0	6060714.pn. and (drain same data)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:13
-	0	438/240, 241, 155, 200, 239, 256, 279 393, 399. ccls. and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:20
-	0	438/240, 241, 155, 200, 239, 256, 279 393, 399. ccls. and (storage adj capacitor) and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:20
-	0	250/370.09, 580, 214.1, ccls. and capacitor and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:32
-	4434	257/295, 296, 297, 298, 299, 300, 301, 302, 303, 304 USPAT 306, 307, 308, 309, 310, 311, 312, 31	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:28

	14	257/295,296,297,298,299,300,301,302,303,304 and (capacitor) and transistor and x-ray and detector	4USPAT306,307,2008/02/01,B10,311,312,31	US-PGPUB; EPO; JPO; DERWENT	12:29
	4	257/295,296,297,298,299,300,301,302,303,304 and (capacitor) and transistor and (x-ray same detector)	4USPAT306,307,2008/02/01,B10,311,312,31	US-PGPUB; EPO; JPO; DERWENT	12:29
	0	250/59,370.09,580,214.1.ccls. and capacitor and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:33	
	0	250/59,370.09,580,214.1.ccls. and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:34	
	150	250/59,370.09,580,214.1.ccls. and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:34	
	25	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:47	
	25	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:35	
	25	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:40	
	0	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and planarazation	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:42	
	2	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and planarization	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:42	
	2	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and planarization	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:44	
	1	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and conformal	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:47	
	20	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and data	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:47	
	10	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and (data adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:48	
	3	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and (data adj line) and (gate adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:49	
	0	10367756.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 15:44	
	2	6020590.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/19 11:58	
	2	6060714.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/19 11:59	

-	2	6124606.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/19 11:59
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